2SD2018

Silicon NPN epitaxial planar type

For low-frequency amplification

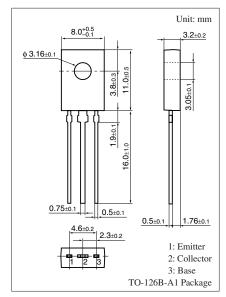
■ Features

- High forward current transfer ratio h_{FE}
- Built-in 60 V Zener diode between base to collector
- Darlington connection

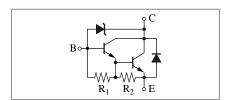
■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base voltage		V_{CBO}	60 +25	V
Collector to emitter voltage		V_{CEO}	60 +25 -10	V
Emitter to base voltage		V_{EBO}	5	V
Collector current		I_C	1	A
Peak collector current		I_{CP}	1.5	A
Collector power	$T_C = 25^{\circ}C$	P_{C}	1.2	W
dissipation	$T_a = 25^{\circ}C^*$		5.0	
Junction temperature		T_j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C

Note) * With a $100 \times 100 \times 2$ mm Al heat sink



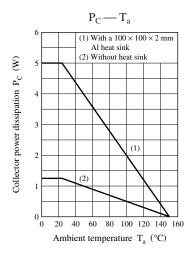
Internal Connection

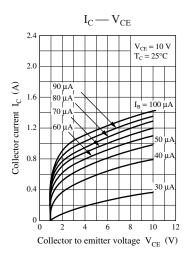


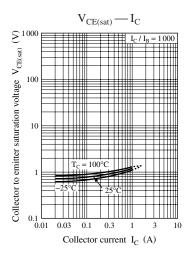
■ Electrical Characteristics $T_C = 25$ °C ± 3 °C

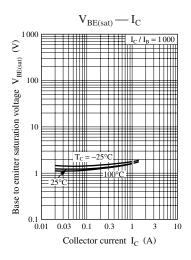
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V_{CBO}	$I_C = 100 \ \mu A, I_E = 0$	50		85	V
Collector to emitter voltage	V_{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	50		85	V
Collector cutoff current	I_{CBO}	$V_{CB} = 25 \text{ V}, I_{E} = 0$			1	μΑ
Emitter cutoff current	I_{EBO}	$V_{EB} = 4 \text{ V}, I_{C} = 0$			2	mA
DC current gain *	h_{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 1.0 \text{ A}$	6500		40 000	
Collector to emitter saturation voltage *	V _{CE(sat)}	$I_C = 1.0 \text{ A}, I_B = 1.0 \text{ mA}$			1.8	V
Base to emitter saturation voltage *	V _{BE(sat)}	$I_C = 1.0 \text{ A}, I_B = 1.0 \text{ mA}$			2.2	V

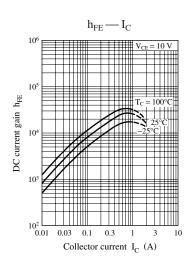
Note) * Pulse measurement

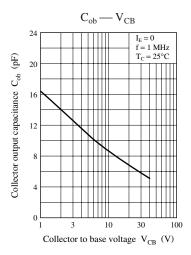












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